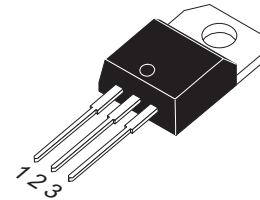


## Description

Passivated high commutation triacs in a plastic envelope intended for use in circuits where high static and dynamic  $dV/dt$  and high  $dI/dt$  can occur. These devices will commute the full rated ms current at the maximum rated junction temperature without the aid of a snubber.

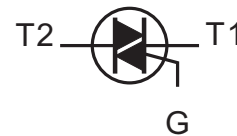
## Simplified outline TO-220AB



## Features

- Blocking voltage to 800 V
- On-state RMS current to 16 A

## Symbol



## Applications

- Motor control
- Industrial and domestic lighting
- Heating
- Static switching

Pin	Description
1	Main terminal 1 (T1)
2	Main terminal 2 (T2)
3	gate (G)
TAB	isolated

SYMBOL	PARAMETER	Value	Unit
$V_{DRM}$	Repetitive peak off-state voltages	800	V
$I_T (RMS)$	RMS on-state current (full sine wave)	16	A
$I_{TSM}$	Non-repetitive peak on-state current (full cycle, $T_j$ initial=25°C)	167	A

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$R_{thj-mb}$	Thermal resistance Junction to mounting base	full cycle	-	-	1.2	K/W
		half cycle	-	-	1.7	K/W
$R_{thj-a}$	Thermal resistance Junction to ambient	in free air	-	60	-	K/W

**Limiting values in accordance with the Maximum system(IEC 134)**

SYMBOL	PARAMETER	CONDITIONS	MIN	Value	UNIT
$V_{DRM}$	Repetitive peak off-state voltages		-	800	V
$I_{T(RMS)}$	RMS on-state current		-	16	A
$I_{TSM}$	Non repetitive surge peak on-state current	full sine wave;	-	200	A
		$T_j = 25^\circ\text{C}$ prior to surge	60Hz 50Hz	167	A
$I^2t$	$I^2t$ for fusing	$t=10\text{ms}$	-	166	$\text{A}^2\text{S}$
$di/dt$	Repetitive rate of rise of on-state current after triggering	$I_{TM}=20\text{A}; I_G=0.2\text{A}_T,$ $di_G/dt=0.2\text{A}/\mu\text{s}$	-	100	$\text{A}/\mu\text{s}$
$I_{GTM}$	Peak gate current		-	2	A
$P_{GM}$	Peak gate power		-	20	W
$P_{G(AV)}$	Average gate power	over any 20 ms period	-	0.5	W
$T_{stg}$	Storage temperature		-40	150	$^\circ\text{C}$
$T_j$	Operating junction temperature		-	125	$^\circ\text{C}$

 **$T_j = 25^\circ\text{C}$  unless otherwise stated**

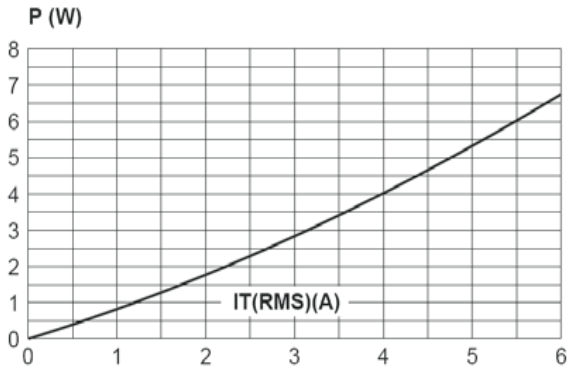
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT	
$I_{GT}$	Gate trigger current	$V_D=12\text{V}; I_T=0.1\text{A}$	QI	-	-	35	mA
			QII	-	-	35	mA
			QIII	-	-	35	mA
$V_{GT}$	Gate trigger voltage	$T_c=25^\circ\text{C}$	-	-	2	V	
$I_{DRM}$	Latching current	$T_c=25^\circ\text{C}$	$T_c=25^\circ\text{C}$	-	-	0.1	mA
			$T_c=100^\circ\text{C}$	-	-	1	mA
			$T_c=125^\circ\text{C}$	-	-	3	mA
$I_H$	Holding current	$V_D=12\text{V}; I_{GT}=0.1\text{A}$	-	-	50	mA	
$V_{TM}$	On-state voltage	$T_c=25^\circ\text{C}$	-	-	1.6	V	
$dV/dt(c)$	Critical rate of rise of off-state voltage	$V_{DM}=67\%V_{DRM(max)}; T_j=110^\circ\text{C};$ exponential waveform; gate open circuit	25	-	-	$\text{V}/\mu\text{s}$	

**Dynamic Characteristics**

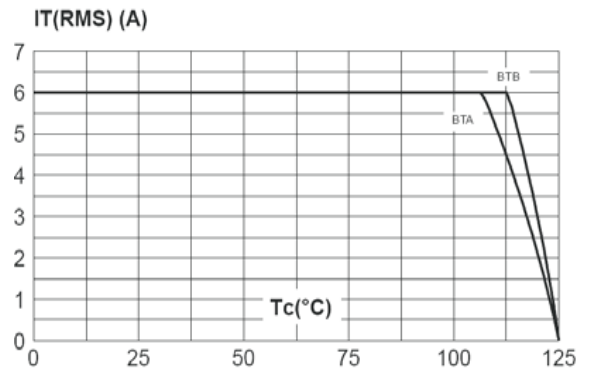
$di_{com}/dt$	Critical rate of change of commutating current	$V_{DM}=400\text{V}; T_j=125^\circ\text{C}; I_{T(RMS)}=16\text{A};$ $dV_{com}/dt=10\text{V}/\mu\text{s};$ gate open circuit	18	-	-	A/ms
$di_{com}/dt$	Critical rate of change of commutating current	$V_{DM}=400\text{V}; T_j=125^\circ\text{C}; I_{T(RMS)}=16\text{A};$ $dV_{com}/dt=0.1\text{V}/\mu\text{s};$ gate open circuit	50	-	-	A/ms

## Description

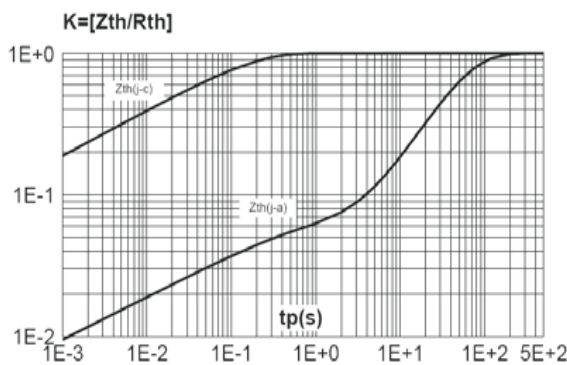
**Fig. 1:** Maximum power dissipation versus RMS on-state current (full cycle).



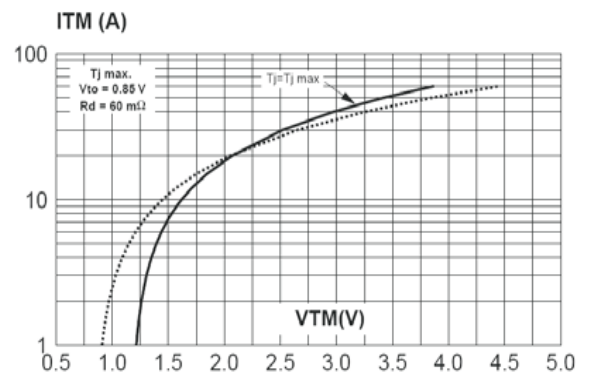
**Fig. 2:** RMS on-state current versus case temperature (full cycle).



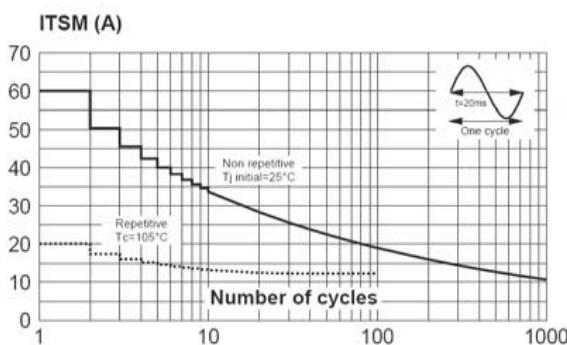
**Fig. 3:** Relative variation of thermal impedance versus pulse duration.



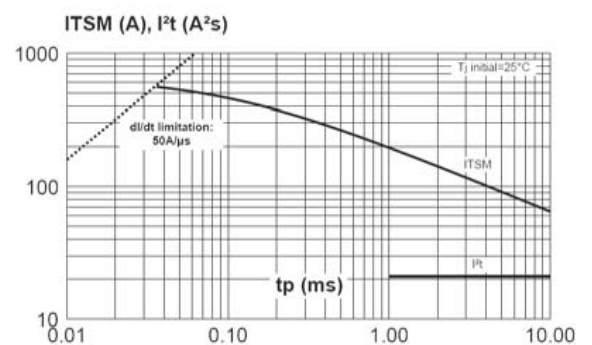
**Fig. 4:** On-state characteristics (maximum values).

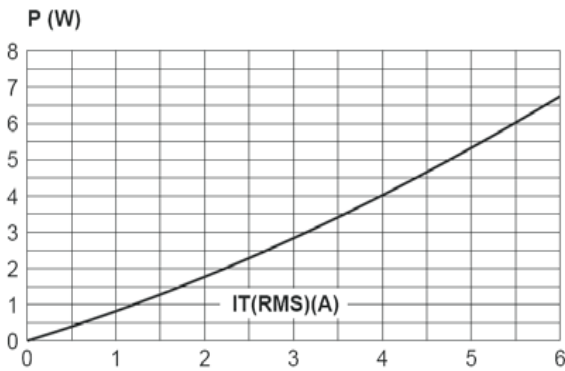
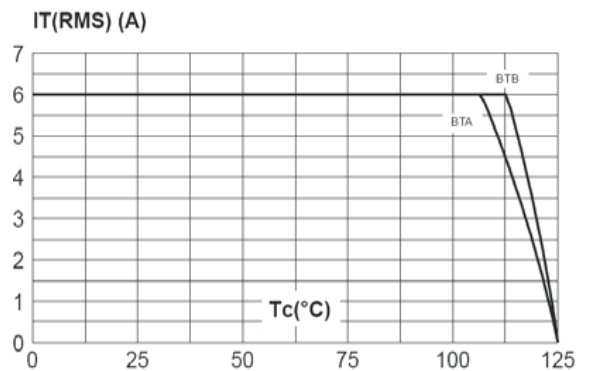
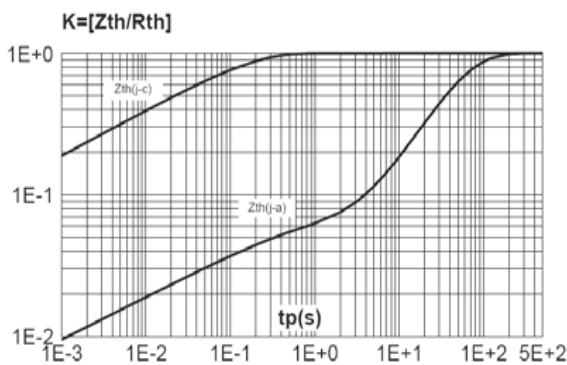
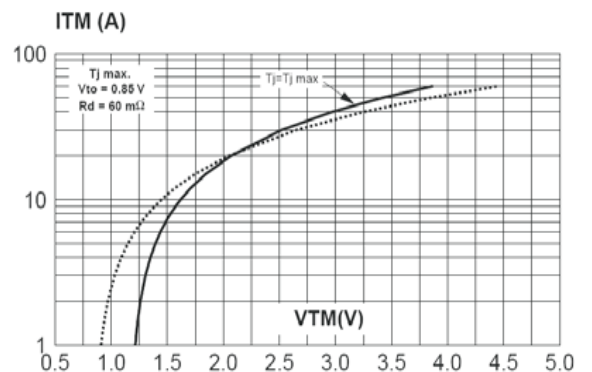
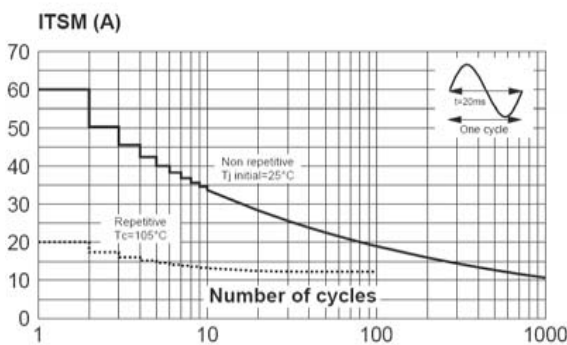
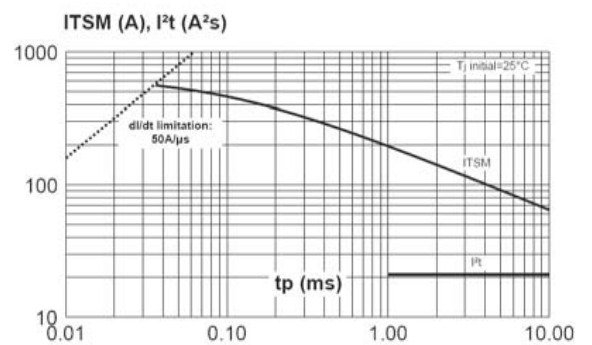


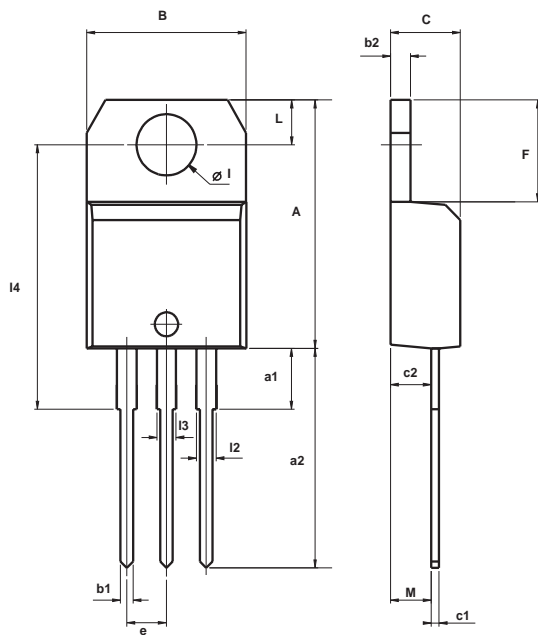
**Fig. 5:** Surge peak on-state current versus number of cycles.



**Fig. 6:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$ .



**Description**
**Fig. 1:** Maximum power dissipation versus RMS on-state current (full cycle).

**Fig. 2:** RMS on-state current versus case temperature (full cycle).

**Fig. 3:** Relative variation of thermal impedance versus pulse duration.

**Fig. 4:** On-state characteristics (maximum values).

**Fig. 5:** Surge peak on-state current versus number of cycles.

**Fig. 6:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $tp < 10\text{ms}$ , and corresponding value of  $I^2t$ .


**Package Mechanical Data**
**TO-220AB (Plastic)**


REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	